

**2-D Materials:
A New Frontier in Energy Storage and Electronics**

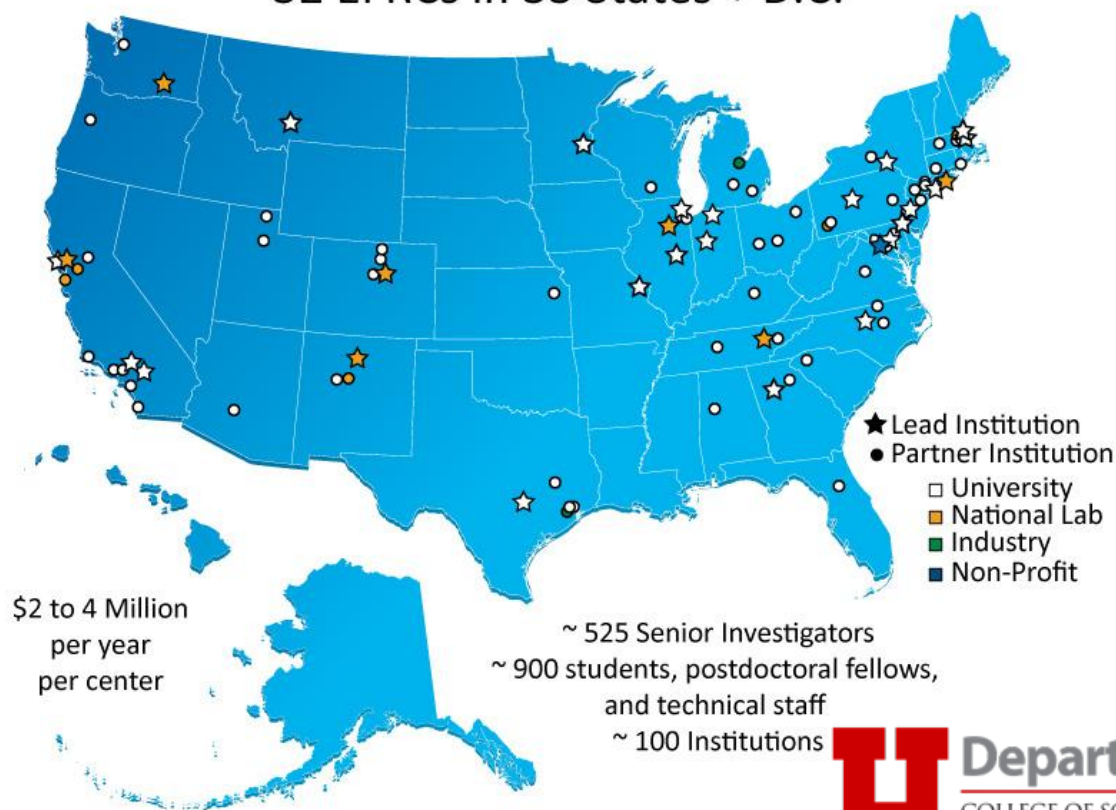
Nano Utah 2015

**Casey Hawkins
13 October 2015**

Energy Frontier Research Center

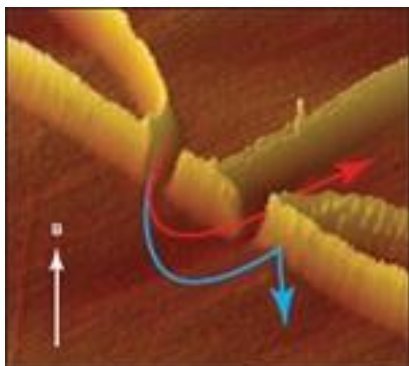
- **integrated, multi-investigator Centers** involve partnerships among universities, national laboratories, nonprofit organizations, and for-profit firms that will conduct fundamental research
- Transforming the way we **generate, supply, transmit, store, and use** energy will be one of the defining challenges for America and the globe in the 21st century.
- Competed 4-5 yr Awards to address **Grand Challenges**

32 EFRCs in 33 States + D.C.

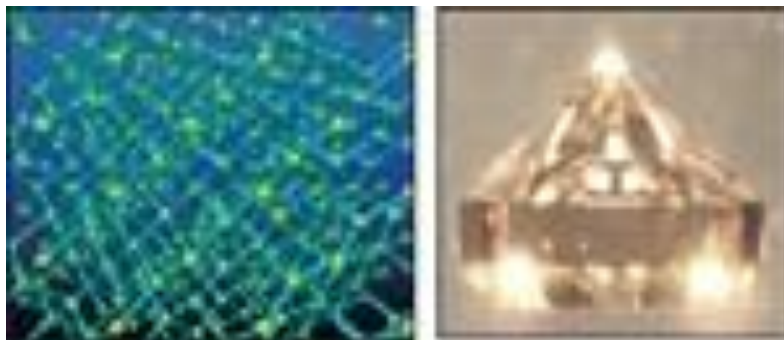


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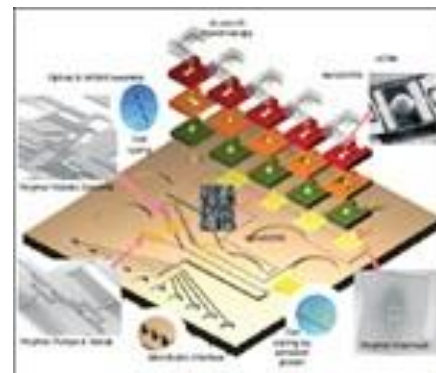
Grand Challenges



How do we **control** materials processes at the level of **electrons**?



How do remarkable properties of matter emerge from **complex correlations of the atomic or electronic constituents** and how can we control these properties?



How can we **master energy and information on the nanoscale** to create new technologies with capabilities **rivalling those of living things**?

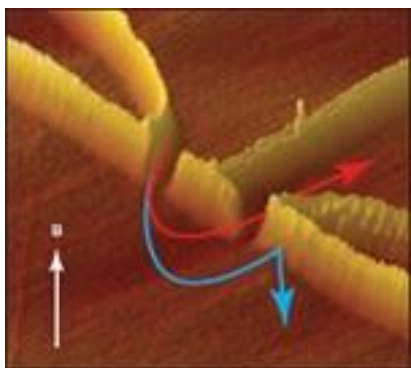


How do we **design revolutionary new forms of matter** with tailored properties?

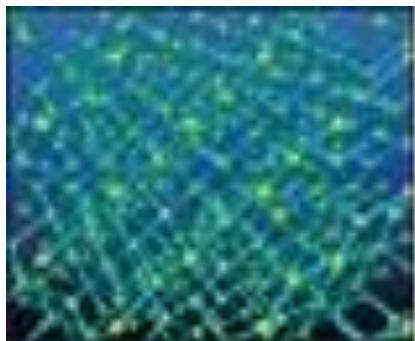
How do we characterize and control matter **away - especially very far away - from equilibrium**?



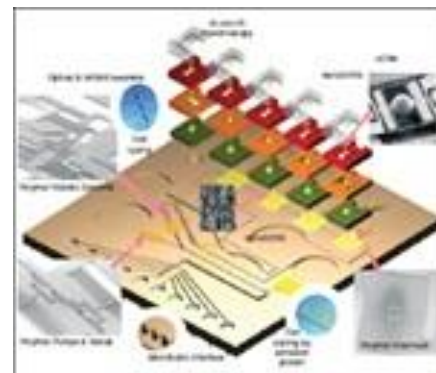
Grand Challenges



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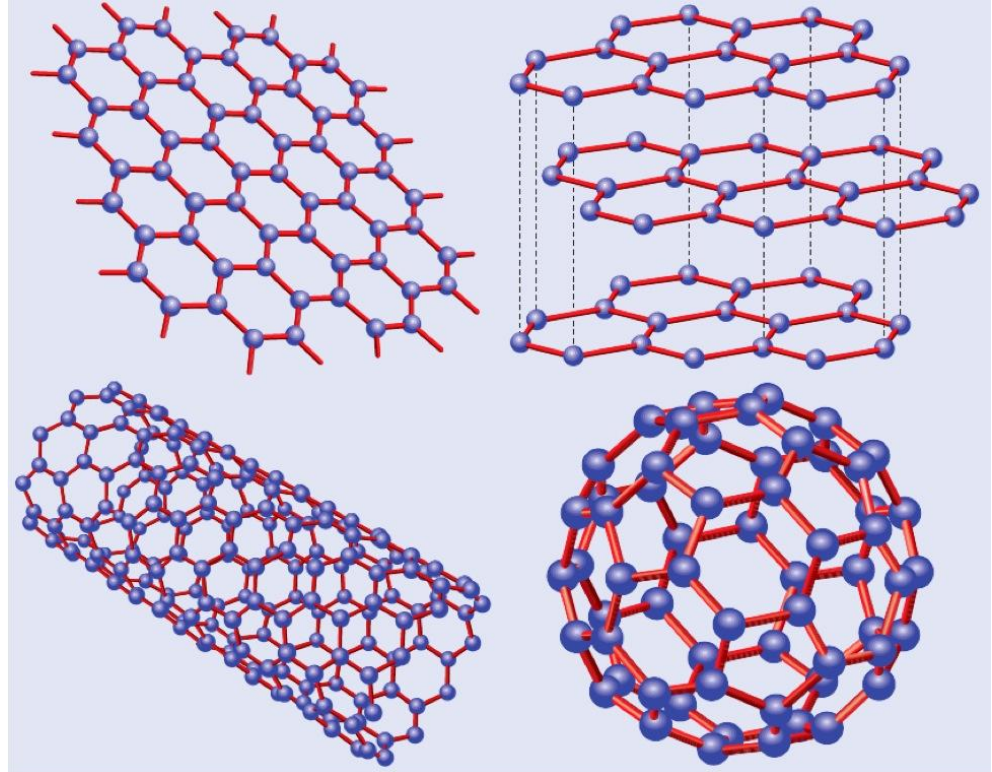
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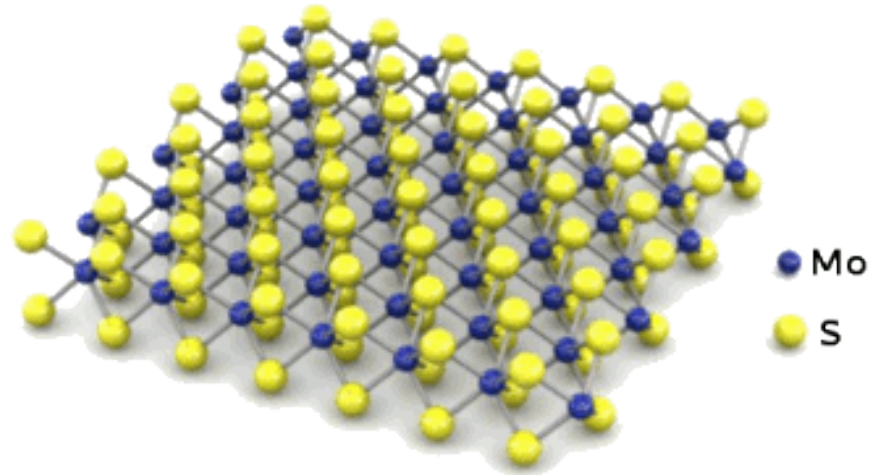
2-D Materials

- Extended 2-D structure



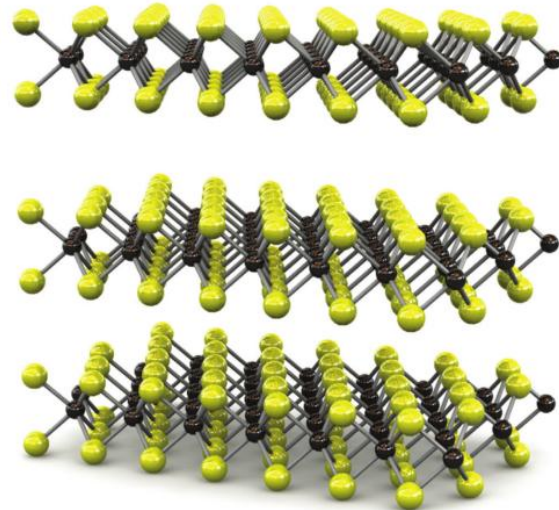
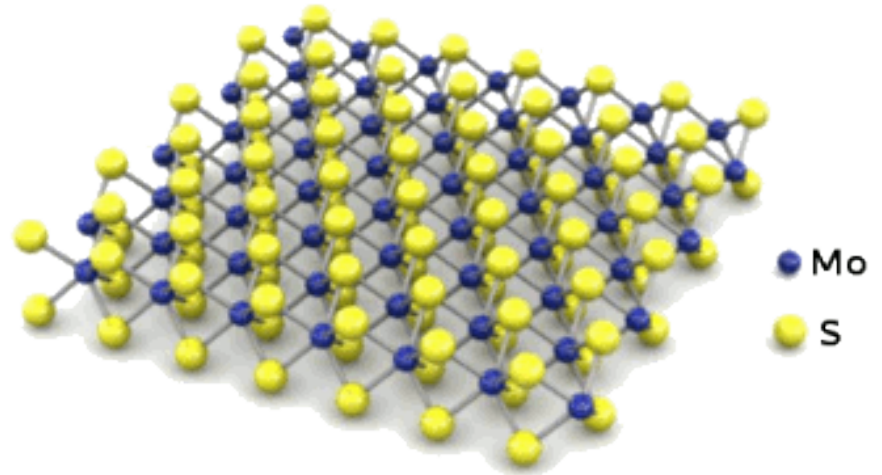
2-D Materials

- Extended 2-D structure



2-D Materials

- Extended 2-D structure
- Weak out-of-plane van der Waals interactions
- Can be cleaved from 3-D bulk material

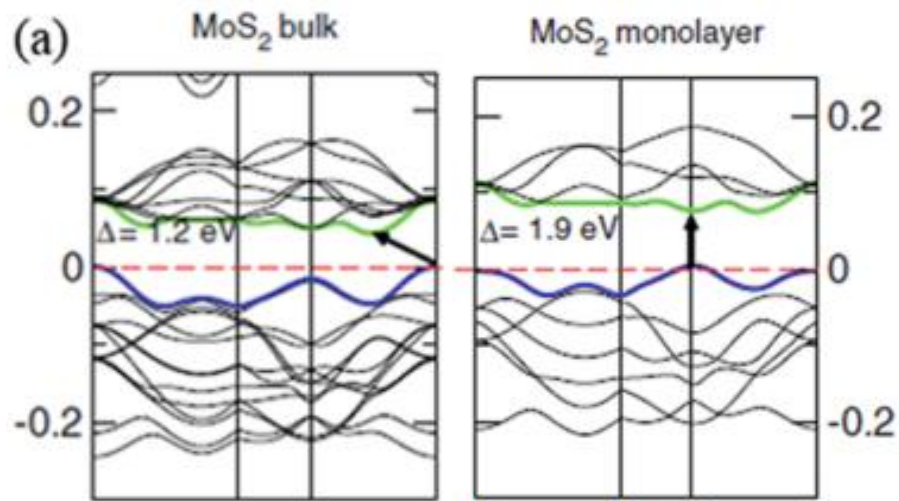


2-D Materials

- Extended 2-D structure
- Weak out-of-plane van der Waals interactions
- Can be cleaved from 3-D bulk material
- Lamellar structure allows for tuning of electronic properties
- Unique electrical, mechanical, and chemical properties

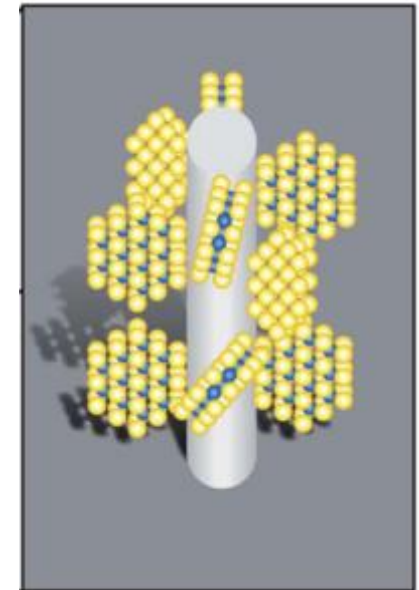
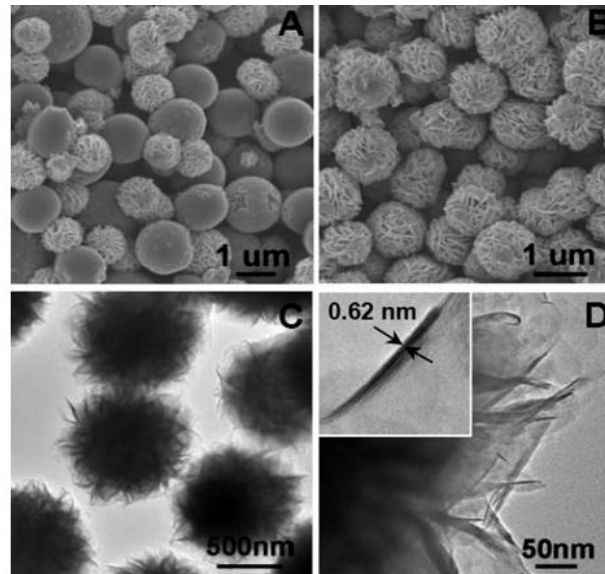
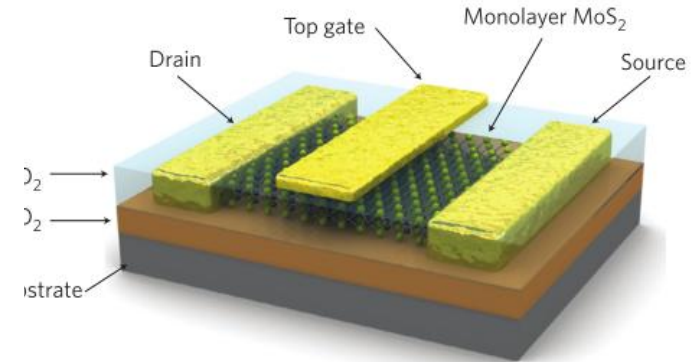
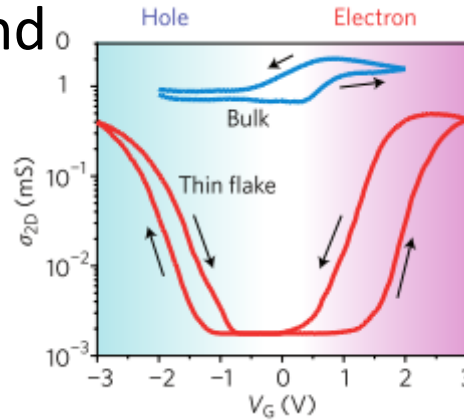
Table 1. Summary of the Band Gaps of Typical Layered TMDs and *h*-BN Materials

2D sheets	theoretical E_g (eV)	experimental E_g (eV)
graphene	0	0
bilayer graphene	0	0
bulk <i>h</i> -BN		5.97 [ref 52]
monolayer <i>h</i> -BN		6.07 [ref 65]
fully hydrogenized <i>h</i> -BN	3.05 [ref 66]	
2–5 layers <i>h</i> -BN		5.92 [ref 105.]
bulk MoS ₂	1.20 (indirect ^b) [refs 35, 139]	1.0–1.29 (indirect) [refs 35, 139]
monolayer MoS ₂ ^a	~1.90 (direct ^b) [ref 140]	~1.90 (direct) [ref 140]
bulk WS ₂	~1.30 (indirect ^b) [refs 35, 147]	~1.35 (indirect) [refs 35, 147]



2-D Material Application

- 2-D materials have found applications in:
 - Optoelectronics
 - Spintronics
 - Catalysts
 - Chemical and biological sensors
 - Supercapacitors
 - Solar cells
 - Field-effect Transistors
 - Lithium ion batteries



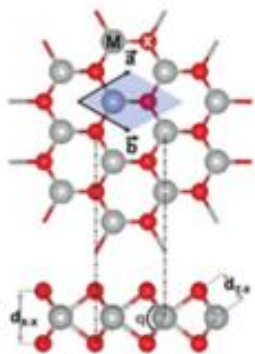
Ding, S., Zhang, D., Chen, J. S. & Lou, X. W. (David). Facile synthesis of hierarchical MoS₂ microspheres composed of few-layered nanosheets and their lithium storage properties. *Nanoscale* **4**, 95–98 (2012)
 Laursen, A. B., Kegnæs, S., Dahl, S. & Chorkendorff, I. Molybdenum sulfides—efficient and viable materials for electro- and photoelectrocatalytic hydrogen evolution. *Energy Environ. Sci.* **5**, 5577 (2012)
 Radisavljevic, B., Radenovic, A., Brivio, J., Giacometti, V. & Kis, A. Single-layer MoS₂ transistors. (2011). doi:10.1038/NNANO.2010.279



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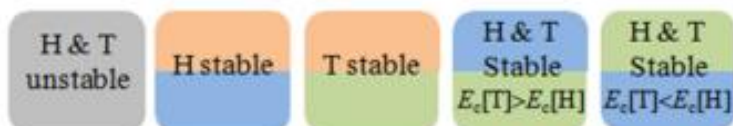
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2-D Transition Metal Dichalcogenides (TMD)



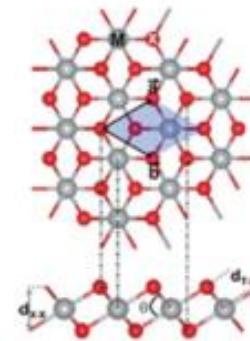
Honeycomb (H) structure

Monolayer transition metal dichalcogenides (MX_2)



E_c : cohesive energy per MX_2 unit
 T^+ : half-metal; T^* & H^+ : metal
 T^{**} & H^{**} : semiconductor (E_g /eV)

direct band gap
 indirect band gap



Centered honeycomb (T) structure

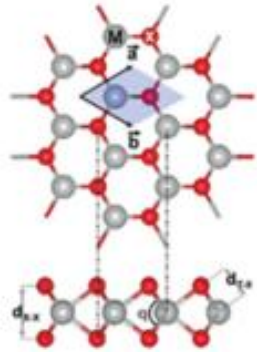
3d							4d		5d	
$H^{**}(1.05)$ ScO ₂ T ⁺	TiO ₂	VO ₂ H ⁺	$H^{**}(0.50)$ CrO ₂ $H^{**}(0.50)$	H ⁺ MnO ₂ $T^{**}(0.28)$	FeO ₂ H ⁺	CoO ₂	NiO ₂ $T^{**}(1.38)$	NbO ₂	$H^{**}(0.97)$ MoO ₂ $H^{**}(0.97)$	$H^{**}(1.37)$ WO ₂ $H^{**}(1.37)$
$H^{**}(0.44)$ ScS ₂ T ⁺	TiS ₂ T ⁺	T ⁺ VS ₂ H ⁺	$H^{**}(1.07)$ CrS ₂ $H^{**}(1.07)$	T ⁺ MnS ₂ T ⁺	FeS ₂ H ⁺	CoS ₂	H ⁺ NiS ₂ $T^{**}(0.51)$	NbS ₂ T ⁺	$H^{**}(1.87)$ MoS ₂ $H^{**}(1.87)$	$H^{**}(1.98)$ WS ₂ $H^{**}(1.98)$
$H^{**}(0.27)$ ScSe ₂ T ⁺	TiSe ₂ T ⁺	H ⁺ VSe ₂ T ⁺	$H^{**}(0.86)$ CrSe ₂ $H^{**}(0.86)$	T ⁺ MnSe ₂ T ⁺	FeSe ₂ H ⁺	CoSe ₂	H ⁺ NiSe ₂ $T^{**}(0.10)$	T ⁺ NbSe ₂ H ⁺	$H^{**}(1.62)$ MoSe ₂ $H^{**}(1.62)$	$H^{**}(1.68)$ WSe ₂ $H^{**}(1.68)$
H ⁺ ScTe ₂ T ⁺	H ⁺ TiTe ₂ T ⁺	H ⁺ VTe ₂ T ⁺	$H^{**}(0.60)$ CrTe ₂ $H^{**}(0.60)$	T ⁺ MnTe ₂ T ⁺	FeTe ₂ H ⁺	CoTe ₂ H ⁺	H ⁺ NiTe ₂ T ⁺	NbTe ₂ T ⁺	$H^{**}(1.25)$ MoTe ₂ $H^{**}(1.25)$	$H^{**}(1.24)$ WTe ₂ $H^{**}(1.24)$



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2-D Transition Metal Dichalcogenides (TMD)

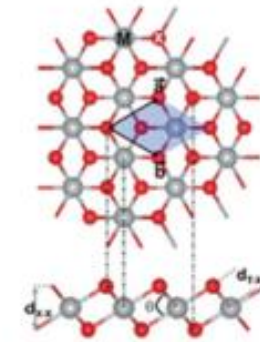
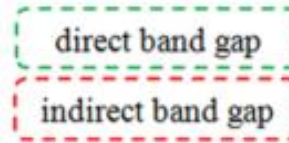


Honeycomb (H) structure

Monolayer transition metal dichalcogenides (MX_2)



E_c : cohesive energy per MX_2 unit
 T^+ : half-metal; T^* & H^+ : metal
 T^{**} & H^{**} : semiconductor (E_g /eV)



Centered honeycomb (T) structure

3d				4d				5d		
$H^{**}(1.05)$ ScO ₂ T ⁺	TiO ₂	VO ₂ H ⁺	CrO ₂ H ^{**} (0.50)	H ⁺ MnO ₂ T ^{**} (0.28)	FeO ₂ H ⁺	CoO ₂	NiO ₂ T ^{**} (1.38)	NbO ₂	MoO ₂ H ^{**} (0.97)	WO ₂ H ^{**} (1.37)
$H^{**}(0.44)$ ScS ₂ T ⁺	TiS ₂ T ⁺	T ⁺ VS ₂ H ⁺	CrS ₂ H ^{**} (1.07)	MnS ₂ T ⁺	FeS ₂ H ⁺	CoS ₂	H ⁺ NiS ₂ T ^{**} (0.51)	NbS ₂ T ⁺	MoS ₂ H ^{**} (1.87)	WS ₂ H ^{**} (1.98)
$H^{**}(0.27)$ ScSe ₂ T ⁺	TiSe ₂ T ⁺	H ⁺ VSe ₂ T ⁺	CrSe ₂ H ^{**} (0.86)	MnSe ₂ T ⁺	FeSe ₂ H ⁺	CoSe ₂	H ⁺ NiSe ₂ T ^{**} (0.10)	T ⁺ NbSe ₂ H ⁺	MoSe ₂ H ^{**} (1.62)	WSe ₂ H ^{**} (1.68)
H ⁺ ScTe ₂ T ⁺	H ⁺ TiTe ₂ T ⁺	H ⁺ VTe ₂ T ⁺	CrTe ₂ H ^{**} (0.60)	MnTe ₂ T ⁺	FeTe ₂ H ⁺	CoTe ₂ H ⁺	H ⁺ NiTe ₂ T ⁺	NbTe ₂ T ⁺	MoTe ₂ H ^{**} (1.25)	WTe ₂ H ^{**} (1.24)

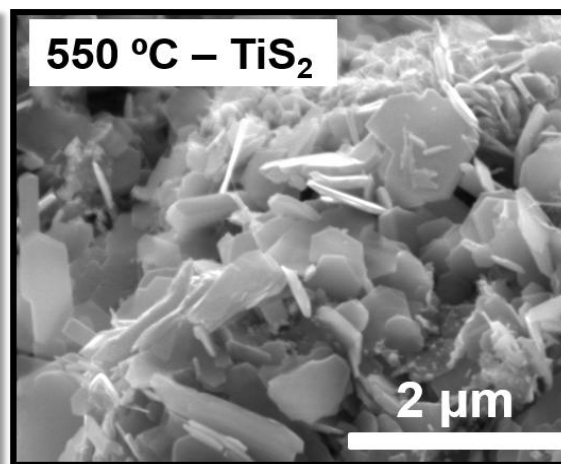
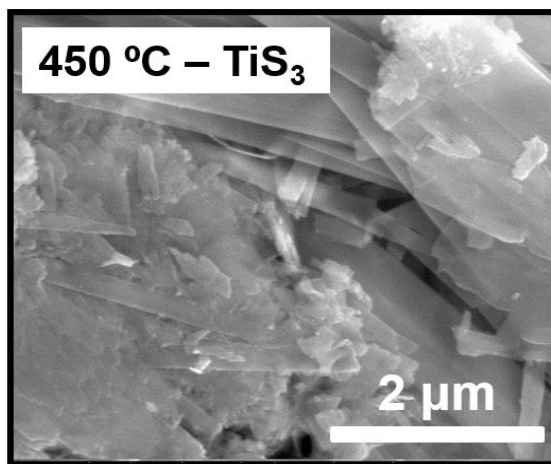
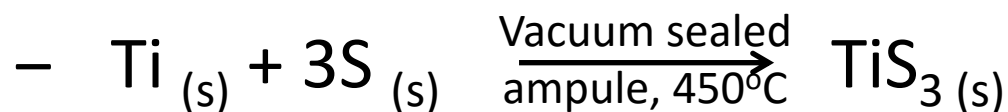
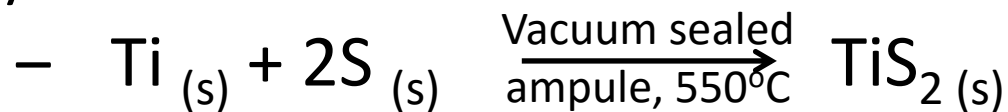


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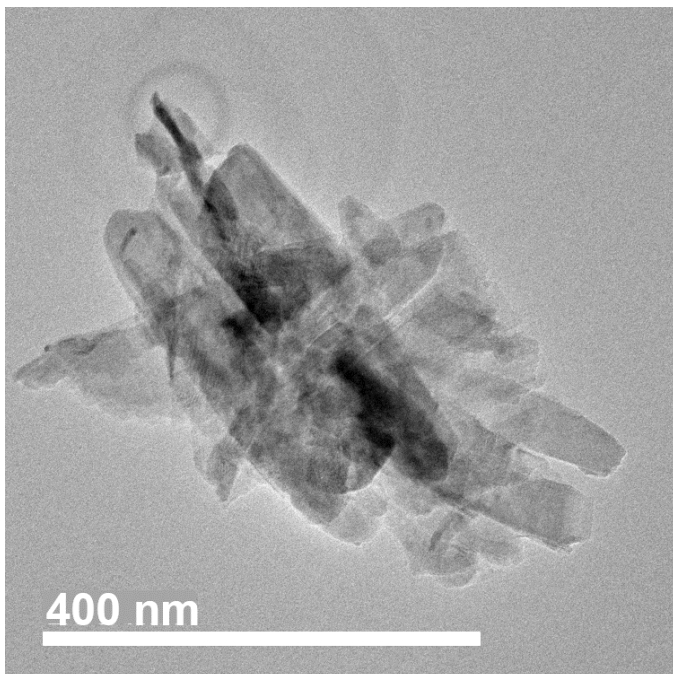
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TiS₂ and TiS₃ TMD Synthesis

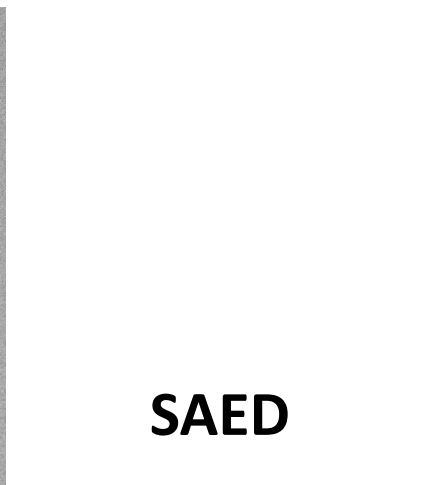
- Challenging to synthesize large scale mono- to few-layered systems
 - Thin film synthesis
 - Electrochemical synthesis
 - Solid-state synthesis



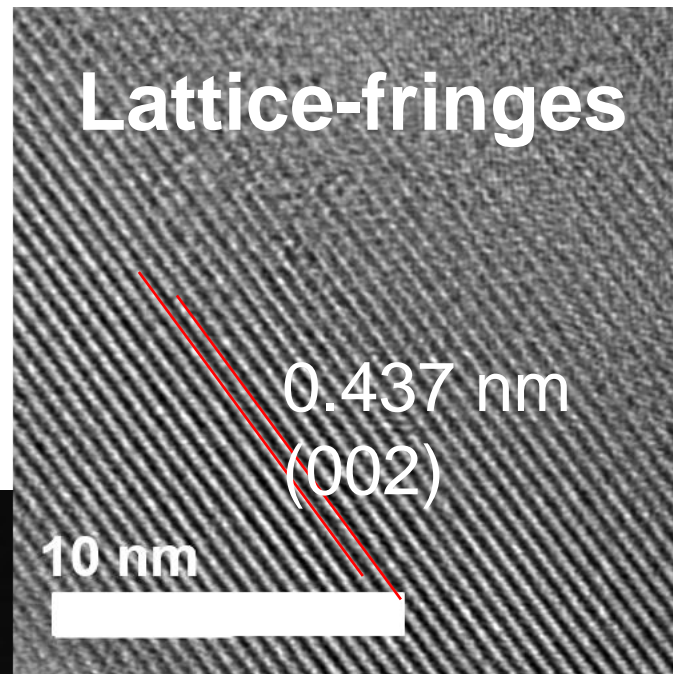
TiS₂ and TiS₃ TMD Structural Analysis



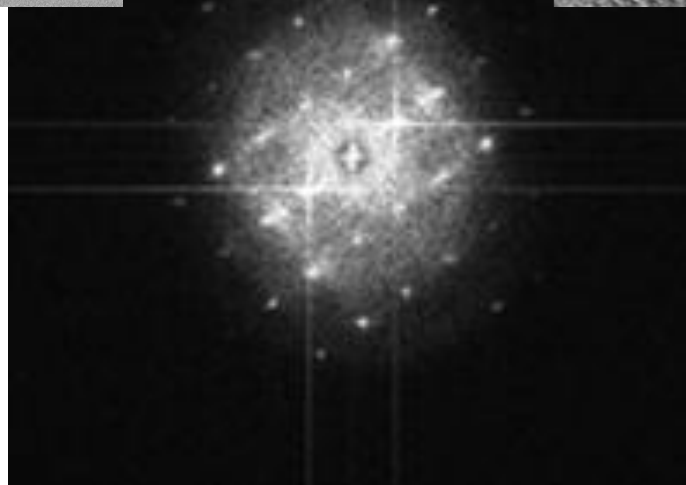
TEM



SAED

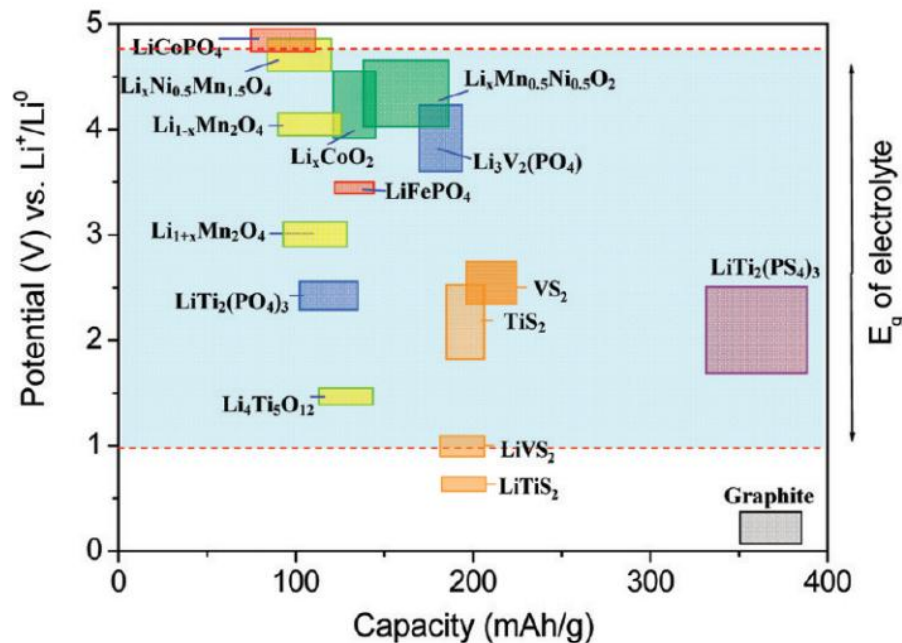
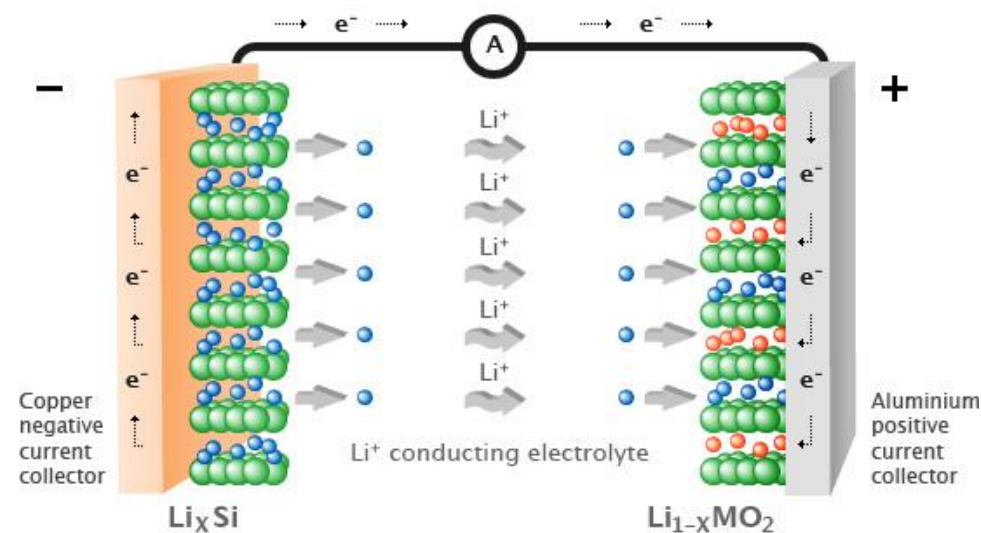


HRTEM



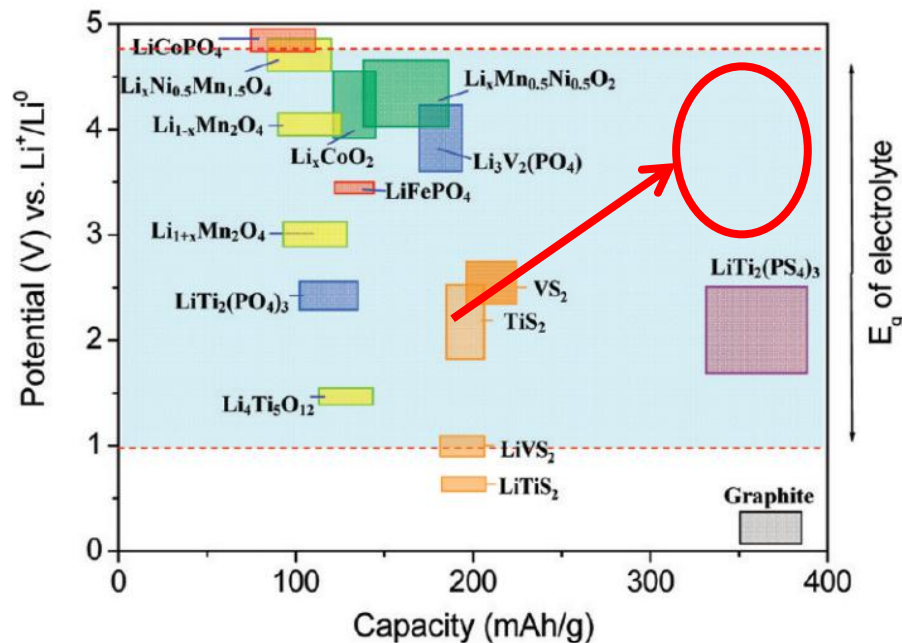
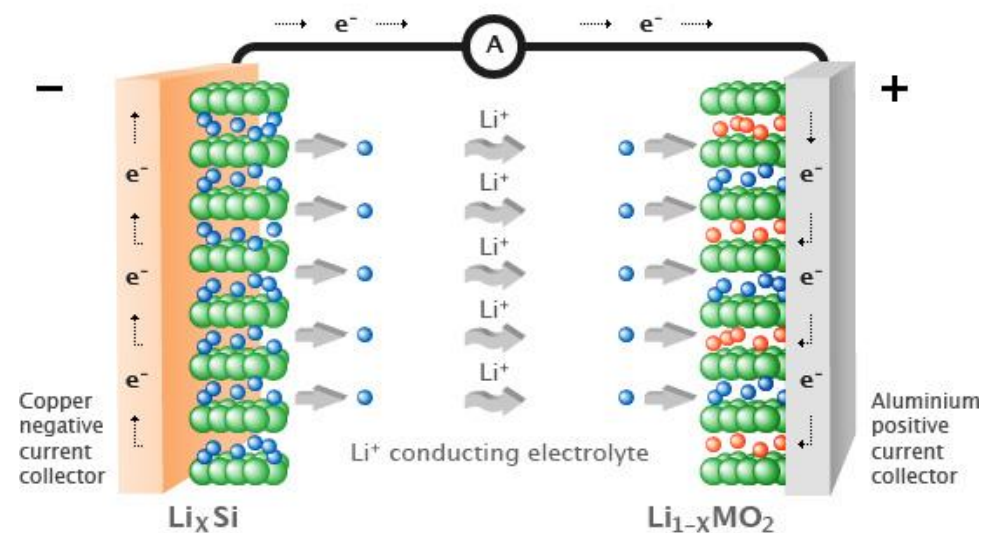
Way Ahead

- Perform complete electronic property workup on TiS_2 and TiS_3
- Incorporate TiS_2 and TiS_3 into Lithium ion batteries
- Explore the electrical properties from mono-layer to bulk
- Explore the effects of dopants on the electrical properties of these systems



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There is research occurring at the University of Utah that is in line with the goals and objectives of the Frontier Energy Research Center's Mission

Questions?